Vishay Semiconductors

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Hyperfast Rectifier, 75 A FRED Pt[®] Gen 5



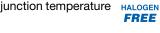
LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS | | | | |
|--|-------------|--|--|--|
| I _{F(AV)} | 75 A | | | |
| V _R | 1200 V | | | |
| V _F at I _F at 150 °C | 2.35 V | | | |
| t _{rr} | 32 ns | | | |
| T _J max. | 175 °C | | | |
| Package | TO-247AD 2L | | | |
| Circuit configuration | Single | | | |

FEATURES

- Hyperfast very low Qrr
- · Designed to optimize hard switching losses
- Optimized for very high speed operations
- 175 °C maximum operating junction temperature
- Polyimide passivation



RoHS

COMPLIANT

 Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for high frequency converters, both soft switched / resonant. Specifically designed to improve efficiency of PFC and output rectification stages of EV / HEV battery charging stations, booster stage of solar inverters and UPS applications, these devices are perfectly matched to operate with MOSFETs or high speed IGBTs.

MECHANICAL DATA

Case: TO-247AD 2L Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RATINGS | | | | |
|--|-----------------------------------|--|-------------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS |
| Repetitive peak reverse voltage | V _{RRM} | | 1200 | V |
| Average rectified forward current | I _{F(AV)} | T _C = 79 °C, D = 0.50 | 75 | |
| Non-repetitive peak surge current | I _{FSM} | T_{C} = 25 °C, t_{p} = 10 ms, sine wave | 300 | А |
| Repetitive peak forward current | I _{FRM} | T _C = 79 °C, D = 0.50, f = 20 kHz | 150 | |
| Operating junction and storage temperature | T _J , T _{Stg} | | -55 to +175 | °C |

| ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified) | | | | | | |
|--|-------------------------------------|---|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 1200 | - | - | |
| Forward voltage | M | I _F = 75 A | - | 3.25 | - | V |
| | V _F | I _F = 75 A, T _J = 150 °C | - | 2.35 | 2.80 | |
| De construction de la construction | I _R | $V_{R} = V_{R}$ rated | - | - | 50 | |
| Reverse leakage current | | $T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$ | - | - | 500 | μA |
| Junction capacitance | CT | V _R = 200 V | - | 36 | - | pF |
| Series inductance | L _S | Measured to lead 5 mm from package body | - | 8 | - | nH |

 Revision: 04-Mar-2025
 1
 Document Number: 97339

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| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | |
|---|------------------|---|--|------|------|-------|---------|
| PARAMETER | SYMBOL | TEST CO | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$ | | - | 32 | - | |
| Reverse recovery time | t _{rr} | T _J = 25 °C | | - | 86 | - | ns |
| | | T _J = 125 °C | I _F = 50 A | - | 140 | - | |
| Peak recovery current | I | | $dI_F/dt = 600 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$ $I_{RR} = 25 \%$ | - | 15 | - | A |
| Feak recovery current | I _{RRM} | T _J = 125 °C | | - | 30 | - | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 735 | - | nC |
| Reverse recovery charge | Q _{rr} | T _J = 125 °C | | - | 2620 | - | |
| Reverse recovery time t _{rr} | + | T _J = 25 °C | I _F = 75 A dI _F /dt = 1000 A/μs V _R = 800 V I _{RR} = 25 % | - | 76 | - | ns |
| | ۲rr | T _J = 125 °C | | - | 120 | - | 115 |
| Peak recovery current | | T _J = 25 °C | | - | 26 | - | A nC |
| | IRRM | T _J = 125 °C | | - | 51 | - | |
| Reverse recovery charge | 0 | T _J = 25 °C | | - | 1270 | - | |
| | Q _{rr} | T _J = 125 °C | | - | 3950 | - | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|-----------------------------------|-------------------------|--------------|------|------------|------------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS |
| Thermal resistance, junction-to-case | R _{thJC} | | - | - | 0.36 | °C/W |
| | | | - | 5.5 | - | g |
| Weight | | | - | 0.2 | - | oz. |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 | - | 175 | °C |
| Marking device | | Case style: TO-247AD 2L | | E5PW | 7512L | |



VS-E5PW7512L-N3

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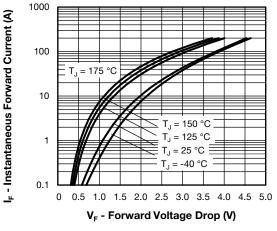


Fig. 1 - Typical Forward Voltage Drop Characteristics

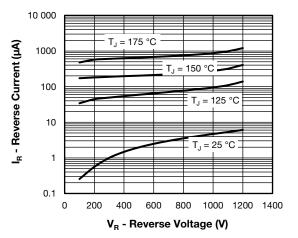


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

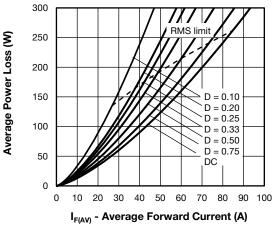


Fig. 5 - Forward Power Loss Characteristics

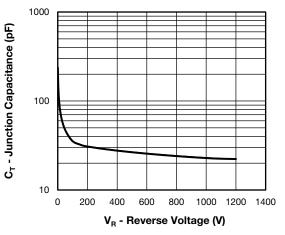


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

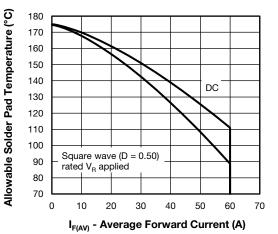


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

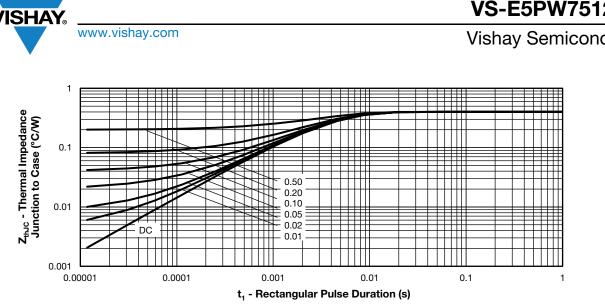
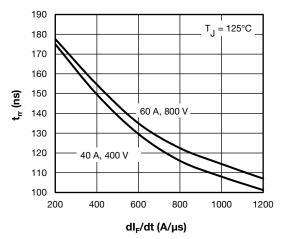
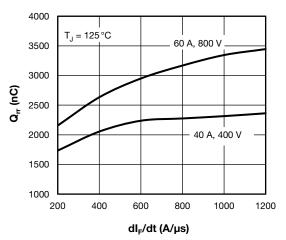
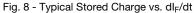


Fig. 6 - Thermal Impedance Z_{thJC} - Characteristics









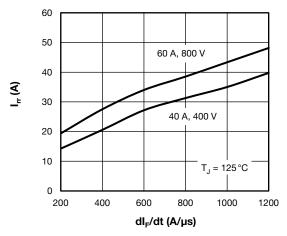


Fig. 9 - Typical Recovery Current vs.dl_F/dt

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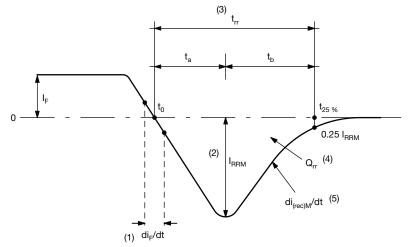


Fig. 10 - Reverse Recovery Waveform and Definitions

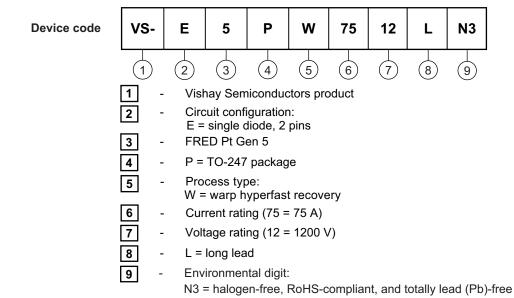
Notes

- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F, to point $t_{25 \%}$, 0.25 I_{RRM} (4) Ü_{rr} - a ed by t_0 and t_{25} %

$$Q_{rr} = \int_{t_0}^{t_{25\%}} I(t) dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE



| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|-------------------|------------------------|-------------------------|--|--|
| PREFERRED P/N | QUANTITY PER TUBE | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-E5PW7512L-N3 | 25 | 500 | Antistatic plastic tube | | |

| LINKS TO RELATED DOCUMENTS | |
|----------------------------|--------------------------|
| Dimensions | www.vishay.com/doc?95536 |
| Part marking information | www.vishay.com/doc?95648 |

Revision: 04-Mar-2025

Document Number: 97339

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Revision: 01-Jan-2025

1